
PF0414A

MOS FET Power Amplifier Module for DCS 1800 Handy Phone

HITACHI

ADE-208-431B (Z)
3rd Edition
December 1997

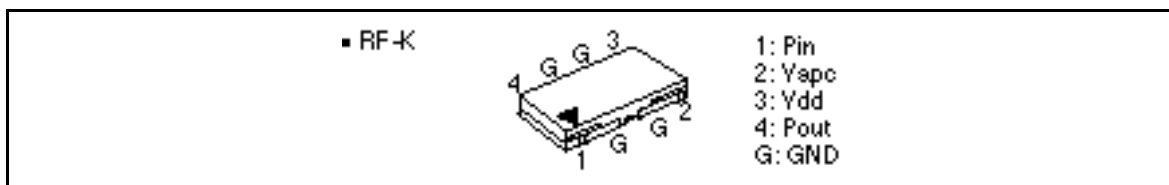
Application

For DCS 1800 class1 1710 to 1785 MHz.

Features

- 3stage amplifier
- Small package: 0.2cc
- High efficiency: 45% Typ
- High speed switching: 0.9 μ sec

Pin Arrangement



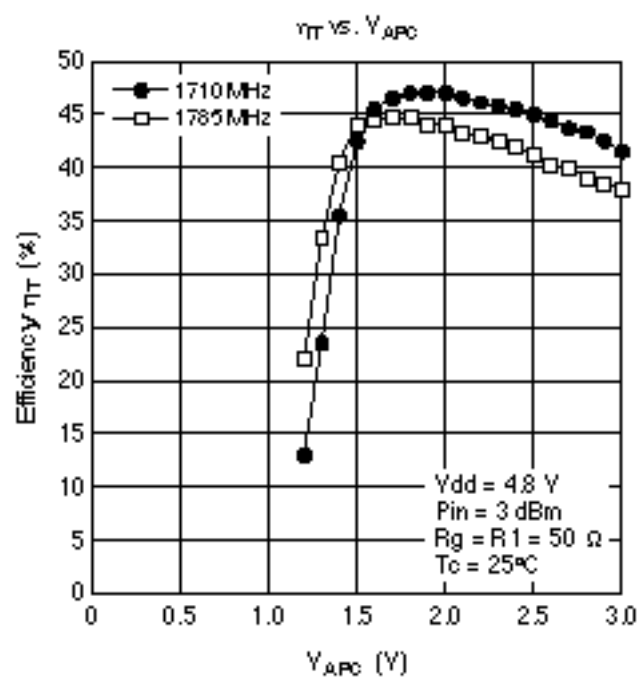
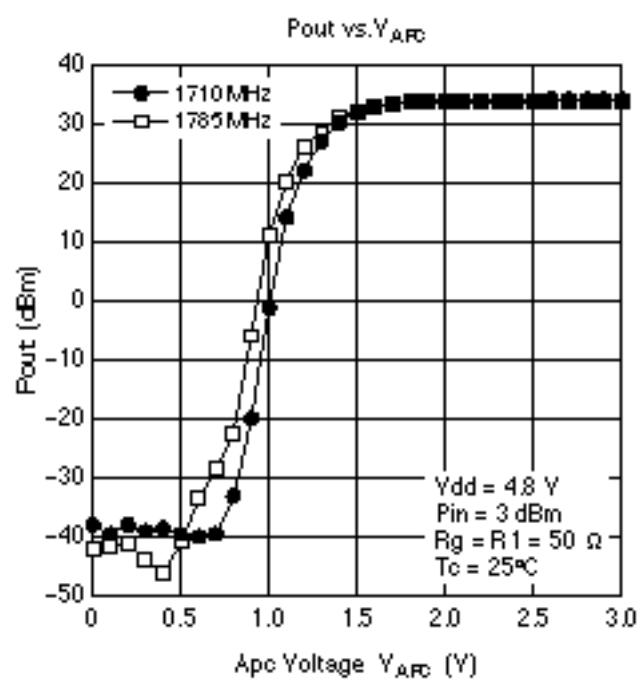
Absolute Maximum Ratings (Tc = 25°C)

Item	Symbol	Rating	Unit
Supply voltage	V_{DD}	11	V
Supply current	I_{DD}	3	A
V_{APC} voltage	V_{APC}	6	V
Input power	Pin	20	mW
Operating case temperature	Tc (op)	-30 to +100	°C
Storage temperature	Tstg	-30 to +100	°C
Output power	Pout	3	W

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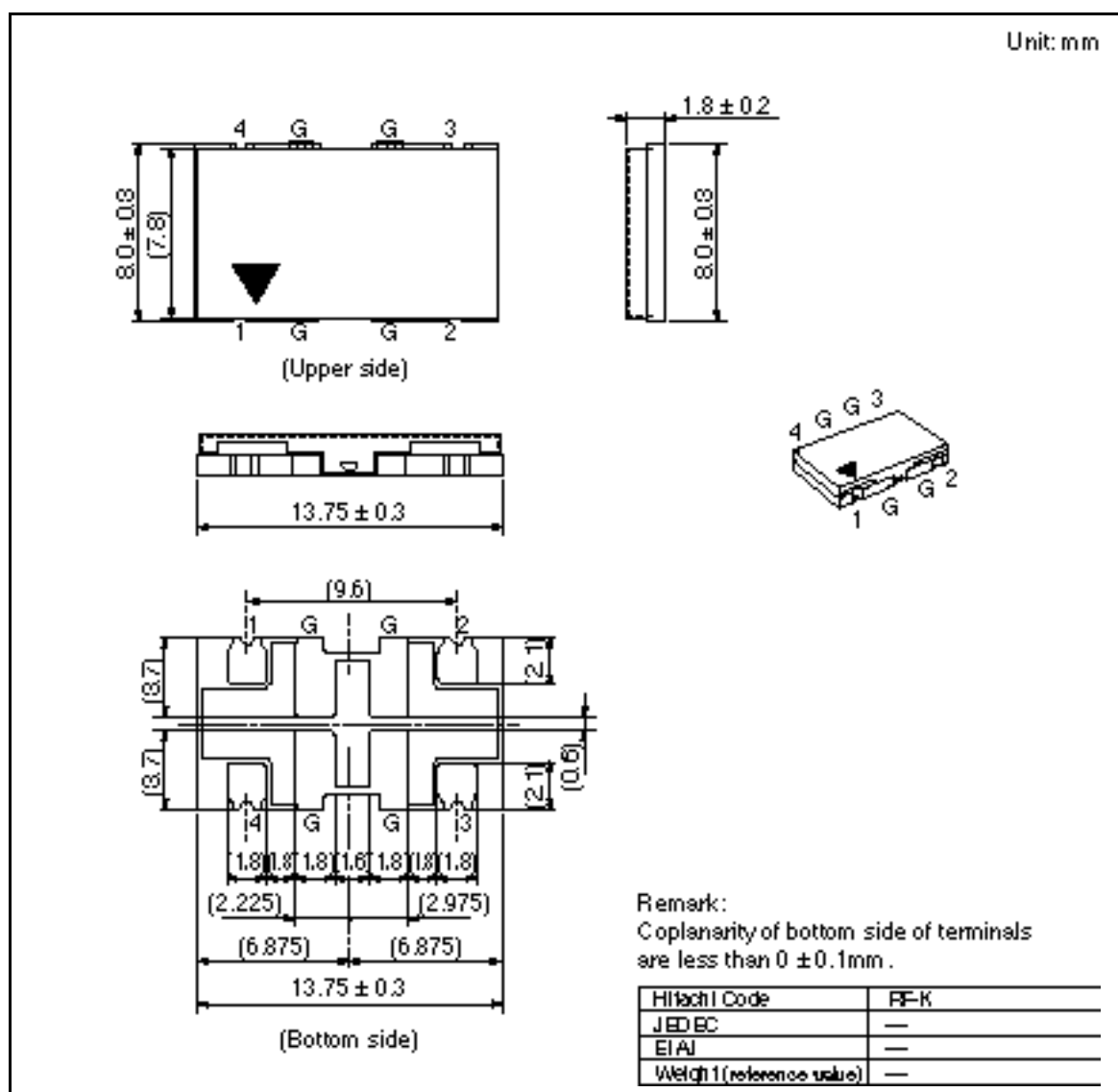
Electrical Characteristics (Tc = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Frequency range	f	1710	—	1785	MHz	
Control voltage range	V _{APC}	0.5	—	3	V	
Drain cutoff current	I _{DS}	—	—	100	μA	V _{DD} = 11 V, V _{APC} = 0 V
Total efficiency	η _T	37	45	—	%	Pin = 2 mW, V _{DD} = 4.8 V,
2nd harmonic distortion	2nd H.D.	—	−45	−35	dBc	Pout = 1.8 W (at APC controlled),
3rd harmonic distortion	3rd H.D.	—	−45	−35	dBc	R _L = R _g = 50 Ω, Tc = 25°C
Input VSWR	VSWR (in)	—	1.5	3	—	
Output power (1)	Pout (1)	2.0	2.4	—	W	Pin = 2 mW, V _{DD} = 4.8 V, V _{APC} = 3 V, R _L = R _g = 50 Ω, Tc = 25°C
Output power (2)	Pout (2)	1.2	1.5	—	W	Pin = 2 mW, V _{DD} = 4.3 V, V _{APC} = 3 V, R _L = R _g = 50 Ω, Tc = 80°C
Isolation	—	—	−40	−30	dBm	Pin = 2 mW, V _{DD} = 4.8 V, V _{APC} = 0.5 V, R _L = R _g = 50 Ω, Tc = 25°C
Switching time	tr, tf	—	0.9	2	μs	Pin = 2 mW, V _{DD} = 4.8 V, Pout = 1.8 W, R _L = R _g = 50 Ω, Tc = 25°C
Stability	—	No parasitic oscillation			—	Pin = 2 mW, V _{DD} = 6 V, Ids = 0.9 A (only pulsed), Pout = 1.8 W (at APC controlled), R _g = 50 Ω, t = 20 sec., Tc = 25°C, Output VSWR = 10 : 1 All phases



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Package Dimensions



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HITACHI

Hitachi, Ltd.

Semiconductor & IC Div.
Nippon Bldg., 2-6-2, Ohite-machi, Chiyoda-ku, Tokyo 100, Japan
Tel: Tokyo (03) 8270-2111
Fax: (03) 8270-5109

For further information write to:

Hitachi America, Ltd.
Semiconductor & IC Div.
2000 Stearns Point Parkway
Brisbane, CA 94005-1885
U.S.A.
Tel: 415-589-8800
Fax: 415-588-4207

Hitachi Europe GmbH
Electronic Components Group
Continental Europe
Domacher Strasse 8
D-85622 Feldkirchen
München
Tel: 089-9 91 80-0
Fax: 089-9 29 80 00

Hitachi Europe Ltd.
Electronic Components Div.
Northern Europe Headquarters
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA
United Kingdom
Tel: 0628-585000
Fax: 0628-778822

Hitachi Asia Pte. Ltd.
16 Collyer Quay #20-00
Hitachi Tower
Singapore 0104
Tel: 585-2100
Fax: 585-1588

Hitachi Asia (Hong Kong) Ltd.
Unit 706, North Tower,
World Finance Centre,
Harbour City Canton Road
Tsim Sha Tsui, Kowloon
Hong Kong
Tel: 27859218
Fax: 27806071

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